NSN 5962-01-413-3429

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Case Outline Source And Designator:
D-5 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Terminal Type And Quantity:
Terminal Type And Quantity: 40 printed circuit
-
40 printed circuit
40 printed circuit Shelf Life:
40 printed circuit Shelf Life: N/a
40 printed circuit Shelf Life: N/a
40 printed circuit Shelf Life: N/a Unit Of Measure:
40 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization:
40 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli
40 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Fiig:
40 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Fiig: